Amendments to the Claims:

1. (Currently Amended) A light emitting device, comprising:
a nitride compound, for providing at least one of blue and ultraviolet emission;
an epoxy, embedded with a phosphor, mounted to the nitride compound,

wherein at least a portion of the emission is initially absorbed by the phosphor; and

- a frame including a <u>roughened</u> surface <u>having a roughened portion</u> contacting the epoxy, the roughened surface includes at least one of ridges, grooves, and dimples to increase an area of the surface contacting the epoxy to facilitate a redirection of an unabsorbed <u>emission backward onto the phosphor</u>.
- 2. (Original) The light emitting device as set forth in claim 1, wherein the compound includes one of binary compound materials, ternary compound materials, and quaternary compound materials.
- 3. (Original) The light emitting device as set forth in claim 2, wherein the nitride compound is one of a group II through group VI-nitride compound.
- 4. (Original) The light emitting device as set forth in claim 3, wherein the nitride compound is a group III-nitride including GaN.
 - 5. (Original) The light emitting device as set forth in claim 1, further including: a substrate, the nitride compound and the epoxy being mounted to the substrate.
- 6. (Original) The light emitting device as set forth in claim 5, wherein the substrate includes sapphire.
 - 7. (Currently Amended) A light emitting device comprising: a nitride compound, for providing at least one of blue and ultraviolet emission; an epoxy, embedded with a phosphor, mounted to the nitride compound; and a frame including an uneven portion that is a designed surface.

- 8. (Original) The light emitting device as set forth in claim 1, wherein the phosphor converts the at least one of the blue and the ultraviolet emission from the nitride compound to a visible light, which is emitted from the frame.
- 9. (Currently Amended) A light emitting device comprising: a nitride compound, for providing at least one of blue and ultraviolet emission; an epoxy, embedded with a phosphor, mounted to the nitride compound; and a frame including a surface having an uneven portion contacting the epoxy and a smooth portion, substantially none of the phosphor embedded epoxy contacting the smooth portion, and

a substrate including:

a first surface, the nitride compound being mounted to the first surface, and

a second surface, opposing the first surface, the epoxy being mounted to the second surface to substantially cover the second surface.

- 10. (Currently Amended) A system for converting light from a first range of wavelengths to a second range of wavelengths, comprising:
 - a semiconductor;
- a phosphor embedded epoxy contacting a first end of the semiconductor, the phosphor converting at least a portion of the first wavelengths into the second wavelengths; and
- a frame contacting the phosphor embedded epoxy, the frame including a surface portion contoured to increase a surface area in contact with the phosphor embedded epoxy, the contoured surface portion including structures arranged to cooperate with the epoxy to redirect unconverted first wavelengths backward into the phosphor.
- 11. (Original) The system for converting light from a first range of wavelengths to a second range of wavelengths as set forth in claim 10, wherein:

the first range of wavelengths includes blue/ultraviolet light; and the second range of wavelengths includes visible light. 12. (Original) The system for converting light from a first range of wavelengths to a second range of wavelengths as set forth in claim 10, wherein:

the first range of wavelengths is greater than about 10 nanometers and less than about 500 nanometers; and

the second range of wavelengths is greater than about 400 nanometers and less than about 800 nanometers.

- 13. (Original) The system for converting light from a first range of wavelengths to a second range of wavelengths as set forth in claim 10, wherein the semiconductor includes:
 - a substrate;
- a nitride compound, for providing at least one of blue and ultraviolet emission, mounted on a first end of the substrate, the phosphor embedded epoxy being mounted on a second end of the substrate.
- 14. (Original) The system for converting light from a first range of wavelengths to a second range of wavelengths as set forth in claim 13, wherein the nitride compound includes one of binary compound materials, ternary compound materials, and quaternary compound materials.
- 15. (Original) The system for converting light from a first range of wavelengths to a second range of wavelengths as set forth in claim 13, wherein the substrate is sapphire.

16-21. (Canceled)

- 22. (Previously Presented) The system for converting light from a first range of wavelengths to a second range of wavelengths as set forth in claim 10, wherein the contoured surface portion includes at least one of ridges, grooves, and dimples.
 - 23. (New) A light emitting device, comprising:
 - a light emitting diode for providing at least one of blue and ultraviolet emission;
 - a frame including a roughened surface; and
- a phosphor containing epoxy disposed between said light emitting diode and said frame and securing the light emitting diode to the roughened surface of the frame.